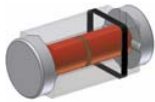
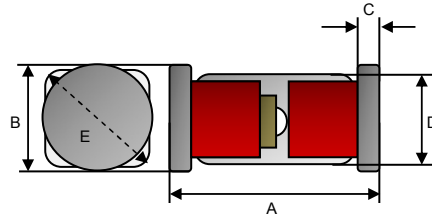


Small Signal Diode



QUADRO Mini-MELF (LS34)
HERMETICALLY SEALED GLASS



Features

- ↪ Wide zener voltage range selection : 2.4V to 75V
- ↪ V_z Tolerance Selection of $\pm 2\%$
- ↪ Moisture sensitivity level 1
- ↪ Matte Tin(Sn) lead finish with Nickel(Ni) underplate
- ↪ Pb free version and RoHS compliant
- ↪ All External Surfaces are Corrosion Resistant and Leads are Readily Solderable

Mechanical Data

- ↪ Case : QUADRO Mini-MELF Package (JEDEC DO-213)
- ↪ High temperature soldering guaranteed : 270°C/10s
- ↪ Polarity : Indicated by cathode band
- ↪ Weight : 29 \pm 2.5 mg

Dimensions	Unit (mm)		Unit (inch)	
	Min	Max	Min	Max
A	3.30	3.70	0.130	0.146
B	1.40	1.60	0.055	0.063
C	0.25	0.40	0.010	0.016
D	1.25	1.40	0.049	0.055
E	1.80		0.071	

Ordering Information

Part No.	Package	Packing
BZT55BXXX L1	QUADRO Mini-MELF	2.5Kpcs / 7" Reel
BZT55BXXX L0	QUADRO Mini-MELF	10Kpcs / 13" Reel

Maximum Ratings and Electrical Characteristics

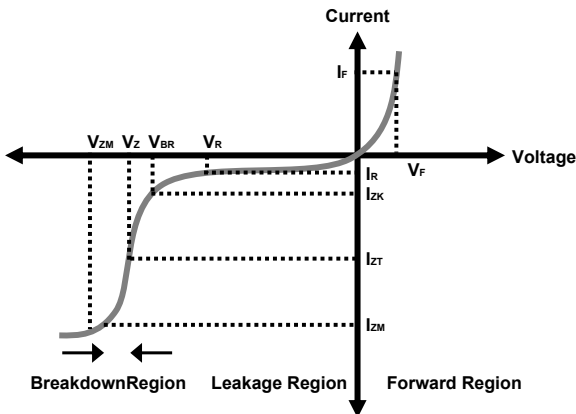
Rating at 25°C ambient temperature unless otherwise specified.

Maximum Ratings

Type Number	Symbol	Value	Units
Power Dissipation	P_D	500	mW
Forward Voltage	$I_F=10mA$ V_F	1.0	V
Thermal Resistance (Junction to Ambient)	(Note 1) $R_{\theta JA}$	500	°C/W
Junction and Storage Temperature Range	T_J, T_{STG}	-65 to + 175	°C

Notes:1. Valid provided that electrodes are kept at ambient temperature

Zener I vs. V Characteristics



- V_{BR} : Voltage at I_{ZK}
- I_{ZK} : Test current for voltage V_{BR}
- Z_{ZK} : Dynamic impedance at I_{ZK}
- I_{ZT} : Test current for voltage V_z
- V_z : Voltage at current I_{ZT}
- Z_{ZT} : Dynamic impedance at I_{ZT}
- I_{ZM} : Maximum steady state current
- V_{ZM} : Voltage at I_{ZM}

Small Signal Diode

Electrical Characteristics

Ta = 25°C unless otherwise noted

V_F Forward Voltage = 1.0V Maximum @ I_F = 10 mA for all part numbers

Part Number	V _Z @ I _{ZT} (Volt)			I _{ZT} (mA)	Z _{ZT} @ I _{ZT} (Ω) Max	I _{ZK} (mA)	Z _{ZK} @ I _{ZK} (Ω) Max	I _R @ V _R (μA) Max	V _R (V)
	Nom	Min	Max						
BZT55B2V4	2.4	2.35	2.45	5	85	1	600	50	1
BZT55B2V7	2.7	2.65	2.75	5	85	1	600	10	1
BZT55B3V0	3.0	2.94	3.06	5	85	1	600	4	1
BZT55B3V3	3.3	3.23	3.37	5	85	1	600	2	1
BZT55B3V6	3.6	3.53	3.67	5	85	1	600	2	1
BZT55B3V9	3.9	3.82	3.98	5	85	1	600	2	1
BZT55B4V3	4.3	4.21	4.39	5	75	1	600	1	1
BZT55B4V7	4.7	4.61	4.79	5	60	1	600	0.5	1
BZT55B5V1	5.1	5.00	5.20	5	35	1	550	0.1	1
BZT55B5V6	5.6	5.49	5.71	5	25	1	450	0.1	1
BZT55B6V2	6.2	6.08	6.32	5	10	1	200	0.1	2
BZT55B6V8	6.8	6.66	6.94	5	8	1	150	0.1	3
BZT55B7V5	7.5	7.35	7.65	5	7	1	50	0.1	5
BZT55B8V2	8.2	8.04	8.36	5	7	1	50	0.1	6.2
BZT55B9V1	9.1	8.92	9.28	5	10	1	50	0.1	6.8
BZT55B10	10	9.80	10.20	5	15	1	70	0.1	7.5
BZT55B11	11	10.78	11.22	5	20	1	70	0.1	8.2
BZT55B12	12	11.76	12.24	5	20	1	90	0.1	9.1
BZT55B13	13	12.74	13.26	5	26	1	110	0.1	10
BZT55B15	15	14.70	15.30	5	30	1	110	0.1	11
BZT55B16	16	15.68	16.32	5	40	1	170	0.1	12
BZT55B18	18	17.64	18.36	5	50	1	170	0.1	13
BZT55B20	20	19.60	20.40	5	55	1	220	0.1	15
BZT55B22	22	21.56	22.44	5	55	1	220	0.1	16
BZT55B24	24	23.52	24.48	5	80	1	220	0.1	18
BZT55B27	27	26.46	27.54	5	80	1	220	0.1	20
BZT55B30	30	29.40	30.60	5	80	1	220	0.1	22
BZT55B33	33	32.34	33.66	5	80	1	220	0.1	24
BZT55B36	36	35.28	36.72	5	80	1	220	0.1	27
BZT55B39	39	38.22	39.78	2.5	90	0.5	500	0.1	28
BZT55B43	43	42.14	43.86	2.5	90	0.5	600	0.1	32
BZT55B47	47	46.06	47.94	2.5	110	0.5	700	0.1	35
BZT55B51	51	49.98	52.02	2.5	125	0.5	700	0.1	38
BZT55B56	56	54.88	57.12	2.5	135	0.5	1000	0.1	42
BZT55B62	62	60.76	63.24	2.5	150	0.5	1000	0.1	47
BZT55B68	68	66.64	69.36	2.5	160	0.5	1000	0.1	51
BZT55B75	75	73.50	76.50	2.5	170	0.5	1000	0.1	56

Notes:

1. The Zener Voltage (V_Z) is tested under pulse condition of 10ms.
2. The device numbers listed have a standard tolerance on the nominal zener voltage of **±2%**.
3. For detailed information on price, availability and delivery of nominal zener voltages between the voltages shown and tighter voltage tolerances, contact your nearest **Taiwan semiconductor** representative.
4. The zener impedance is derived from the 60-cycle ac voltage, which results when an ac current having an rms value equal to 10% of the DC zener current (I_{ZT} or I_{ZK}) is superimposed to I_{ZT} or I_{ZK}.

Small Signal Diode

Rating and Sharacteristic Curves

FIG 1 Typical Forward Characteristics

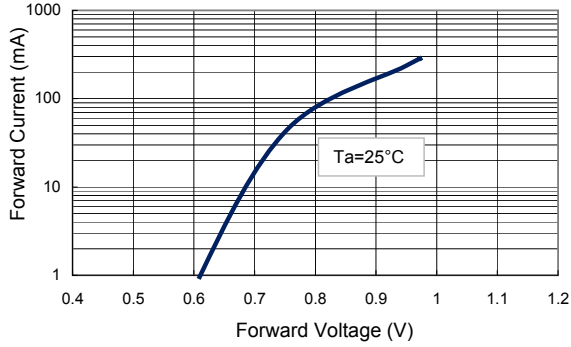


FIG 2 Zener Breakdown Characteristics

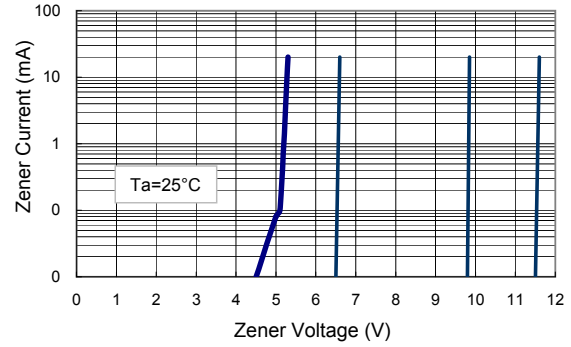


FIG 3 Zener Breakdown Characteristics

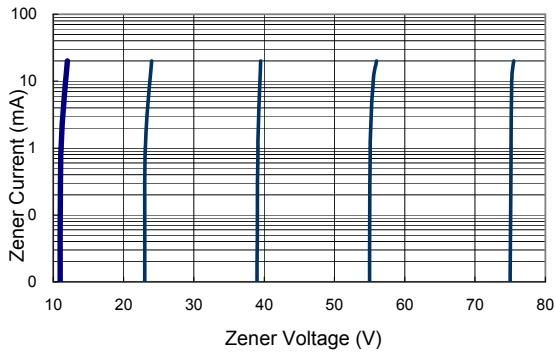


FIG 4 Admissible Power Dissipation Curve

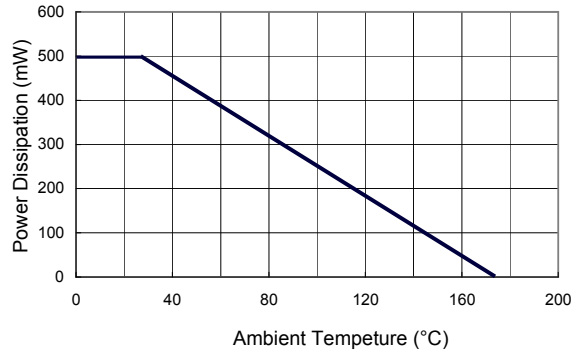


FIG 5 Typical Capacitance

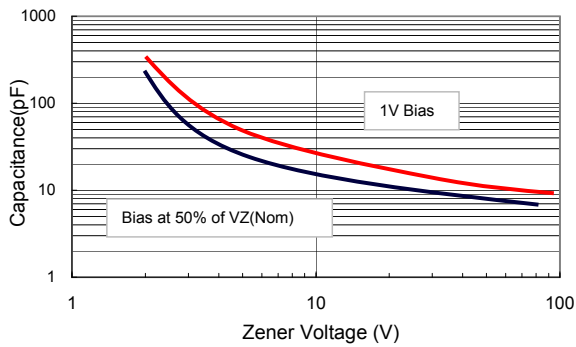


FIG 6 Effect of Zener Voltage on Impedance

